

Strong-coupling surface polaron in a magnetic field

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Abstract

By applying variational method, the strong electron-surface optical(SO) phonon interaction and the weak electron-longitudinal optical (LO) phonon interaction are studied systematically in present paper. The formula of induced energy V_{e-so} , V_{e-lo} in both the ground and excited states are given. The numerical results show that as the distance between the electron and the polar crystal surface increases, the electron-LO phonon interaction energy increases yet the electron-SO phonon interaction energy decreases. The numerical results also show that both electron-LO and electron-SO phonon interaction are enhanced as the magnetic field strength increases.

Key words: Semiconductors, Electron-phonon interactions

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1. Introduction

The behavior of polaron has received much attention in the past decades [1,2]. Huybrechts [3] proposed a linear combination operator method and investigated the property of polaron in strong electron-phonon coupling case. Tokuda [4] added another variational parameter to the momentum operator and studied the ground-state energy and effective mass of the bulk polaron. Gu [5] discussed the the ground-state energy, the first-excited state energy and the effective mass of intermediate-coupling polaron in a polaron slab. When external magnetic field is applied to the electron-phonon interaction system, the property of magnetopolaron attracted many investigators' interests. Whitfield *et al* [6] studied the effectiveness of adiabatic approximation theory for a polaron in a magnetic field and they found that the usual adiabatic theory applied to a polaron in a strong magnetic field does not give the right weak coupling limit. Ercelebi [7] studied the two-dimensional magnetopolaron in the strong-coupling regime and proposed a modified coherent phonon state. Hai, Peeters *et al* [8] did research into the polaron-cyclotron-resonance spectrum resulting from interface- and slab-phonon modes in a GaAs/AlAs quantum well and an experiment was done to investigate the resonant magnetopolaron effects due to interface phonons in GaAs/AlGaAs multiple quantum well structures by Wang, Nickle *et al* [9]. Recently, the author etc have studied the electron self-energy and effective mass by the powerful Green's function method [10].

For the bulk polaron, the perturbation theory is applicable when $\alpha_l < 1$ and the LLP(Lee-Low-Pines) variational method is effective when $\alpha_l < 6$. For the surface polaron, Pan [11] showed that when the electron-surface optical(SO) phonon coupling constant $\alpha_s > 2.5$, the strong coupling theory must be applied. Therefor ,in some polar crystals, the weak electron-LO phonon coupling and strong electron-SO phonon coupling should be considered together. So far, the research work in such a field has been scarce

In the present paper, using variational method and taking weak electron-LO phonon and strong electron-SO phonon interaction into account, we give the ground and excited states energies of the system, the electron-LO phonon interaction induced energy V_{e-LO} and the electron-SO phonon interaction induced energy V_{e-SO} . Using polar crystal AgBr as an example, numerical evaluation are also presented.

2. Theory

Considering the following system: the semi-infinite space $z > 0$ is occupied by the AgBr

crystal, whereas the space $z < 0$ is a vacuum. The external magnetic field is applied along the z direction and an electron is moving in the polar crystal. $\mathbf{B}=(0,0,B)$, choosing the symmetric gauge for the vector potential, i.e. $\mathbf{A}=\mathbf{B}/2(-y,x,0)$, the Hamiltonian describing an electron coupled to both LO phonons and SO phonons can be written as($\hbar = m_b=1$, m_b is the band mass of the electron)

$$H = H_0 + H_{\perp} + H_{e-ph} = H_{\perp} + H_{//} , \quad (1)$$

$$H_0 = \frac{P_{//}^2}{2} + \frac{\omega_c^2}{8}(x^2 + y^2) + \frac{\omega_c}{2}L_z + \sum_k \omega_{lo} a_k^{\dagger} a_k + \sum_q \omega_{so} b_q^{\dagger} b_q , \quad (2)$$

$$H_{\perp} = \frac{P_z^2}{2} + \frac{e^2(\varepsilon_{\infty} - 1)}{4z\varepsilon_{\infty}(\varepsilon_{\infty} + 1)} , \quad (3)$$

$$H_{e-ph} = H_{e-lo} + H_{e-so} , \quad (4)$$

$$H_{e-lo} = \sum_k [V_k^* \sin(zk_z) \exp(-ik_{//} \cdot \rho) a_k^{\dagger} + h.c.] , \quad (5)$$

$$H_{e-so} = \sum_q [V_q^* \exp(-qz) \exp(-iq \cdot \rho) b_q^{\dagger} + h.c.] . \quad (6)$$

where

$$V_k^* = i \left(\frac{4\pi e^2 \omega_{lo}}{\varepsilon V} \right)^{\frac{1}{2}} \frac{1}{k} , \quad \frac{1}{\varepsilon} = \frac{1}{\varepsilon_{\infty}} - \frac{1}{\varepsilon_0} .$$

$$V_q^* = i \left(\frac{\pi e^2 \omega_{so}}{\varepsilon^* q A} \right)^{\frac{1}{2}} , \quad \frac{1}{\varepsilon^*} = \frac{\varepsilon_0 - 1}{\varepsilon_0 + 1} - \frac{\varepsilon_{\infty} - 1}{\varepsilon_{\infty} + 1} .$$

In the above equations, $a_k^{\dagger}(a_k)$ is the creation(annihilation) operator of bulk LO phonons with three-dimensional wave vector k , $b_k^{\dagger}(b_k)$ is the corresponding operator for the SO phonons with two-dimensional wave vector q . $P_{//} = (p_x, p_y)$ and $\rho = (x, y)$ are the electron momentum and position vector in xy plane, respectively, and p_z is the electron momentum in z direction. $k_{//} = (k_x, k_y)$ is phonon wave vector in the xy plane. ω_{lo} and ω_{so} are the frequencies of the bulk LO and SO phonons. ε_0 and ε_{∞} are the static and high-frequencies dielectric constant of the crystal respectively. A and V are the surface area and the volume of the crystal.

The polaron system wave function can be separated into the electron and the phonon parts.

$$|\psi\rangle = |\phi_e\rangle |\phi_{ph}\rangle \quad (7)$$

With $|\phi_{ph}\rangle = u_1 u_2 |0\rangle$, $|0\rangle$ is the phonon ground state, and the explicit form of u_1, u_2 will be introduced in the following.

Let us start from the unitary transformation:

$$u_1 = \exp(-i(\sum_k a_1 a_k^\dagger a_k k_{//} \cdot \rho + \sum_q a_2 b_q^\dagger b_q q \cdot \rho)) \quad (8)$$

With $a_1 = 1$ and $a_2 = 0$ corresponding to the weak-coupling limit case and the strong-coupling limit case respectively. The parts of polaron Hamiltonian can be transformed into:

$$H'_0 = u_1^{-1} H_0 u_1 = \frac{1}{2}(P_{//} - \sum_k a_k^\dagger a_k k_{//})^2 + \frac{\omega_c^2}{8}(x^2 + y^2) + \frac{\omega_c}{2} L_z \\ + \frac{\omega_c}{2} \sum_k a_k^\dagger a_k (y k_x - x k_y) + \sum_k \omega_{lo} a_k^\dagger a_k + \sum_q \omega_{so} b_q^\dagger b_q, \quad (9)$$

$$H'_{e-lo} = u_1^{-1} H_{e-lo} u_1 = \sum_k [V_k^* \sin(z k_z) a_k^\dagger + h.c.] , \quad (10)$$

$$H'_{e-so} = u_1^{-1} H_{e-so} u_1 = \sum_q [V_q^* \exp(-qz) \exp(-iq \cdot \rho) b_q^\dagger + h.c.] , \quad (11)$$

$$H'_\perp = u_1^{-1} H_\perp u_1 = H_\perp . \quad (12)$$

Following the scheme of Huybrechts, we introduce the creation and annihilation operators $c_j^\dagger$ and c_j by

$$p_j = \frac{\sqrt{\lambda}}{2}(c_j^\dagger + c_j) , \quad (13)$$

$$\rho_j = \frac{i}{\sqrt{\lambda}}(c_j - c_j^\dagger) . \quad (14)$$

Where the subscript j refers to the x and y directions, λ is the variational parameter, and $c_j^\dagger(c_j)$ is Boson operator.

Rewriting (9), (11) using (13), (14), one gets:

$$H'_0 = \frac{\lambda}{8} [\sum_j (c_j^\dagger c_j^\dagger + c_j c_j) + \sum_j (c_j^\dagger c_j + c_j c_j^\dagger)] - \frac{\sqrt{\lambda}}{2} \sum_{k,j} a_k^\dagger a_k k_{//j} (c_j^\dagger + c_j) \\ + \frac{1}{2} \sum_k a_k^\dagger a_k k_{//}^2 + \frac{1}{2} \sum_{k,k'} a_k^\dagger a_{k'}^\dagger a_k a_{k'} k_{//} k'_{//} + \frac{\omega_c^2}{8\lambda} \sum_j (c_j c_j^\dagger + c_j^\dagger c_j) \\ - \frac{\omega_c^2}{8\lambda} \sum_j (c_j^\dagger c_j^\dagger + c_j c_j) + \frac{i\omega_c}{2} (c_x c_y^\dagger - c_x^\dagger c_y) + \sum_k \omega_{lo} a_k^\dagger a_k + \sum_q \omega_{so} b_q^\dagger b_q \\ + \frac{i\omega_c}{2\sqrt{\lambda}} \sum_k a_k^\dagger a_k [k_x (c_y - c_y^\dagger) - k_y (c_x - c_x^\dagger)] , \quad (15)$$

$$H'_{e-so} = \sum_q [V_q^* \exp(-qz) \exp(\sum_j \frac{q_j}{\sqrt{\lambda}} (c_j - c_j^\dagger)) b_q^\dagger + h.c.] , \quad (16)$$

Yet, H'_{e-lo} and $H'_\perp$ are invariable in forms. Let continue to do the u_2 transformation:

$$u_2 = \exp\left[\sum_k (a_k^\dagger f_k e^{-ik_{//}\cdot\rho_0} - a_k f_k^* e^{ik_{//}\cdot\rho_0}) + \sum_q (b_q^\dagger g_q e^{-iq\cdot\rho_0} - b_q g_q^* e^{iq\cdot\rho_0})\right] \quad (17)$$

Where $f_k(f_k^*)$ and $g_q(g_q^*)$ are variational parameters, and $\rho_0 = (x_0, y_0)$ is the electron orbit center where $x_0 = x/2 - p_y/\omega_c$, $y_0 = y/2 + p_x/\omega_c$. The necessity of making the phonon deformation centered at ρ_0 was emphasized in an elaborate discussion by Whitfield *et al* [6].

$$u_2^{-1} a_k u_2 = a_k + f_k e^{-ik_{//}\cdot\rho_0}, \quad u_2^{-1} a_k^\dagger u_2 = a_k^\dagger + f_k^* e^{ik_{//}\cdot\rho_0}, \quad (18)$$

$$u_2^{-1} b_q u_2 = b_q + g_q e^{-iq\cdot\rho_0}, \quad u_2^{-1} b_q^\dagger u_2 = b_q^\dagger + g_q^* e^{iq\cdot\rho_0}. \quad (19)$$

Performing u_2 transformation and using (18) and (19), one can get H''_0 , H''_{e-lo} and H''_{e-so} after lengthy calculation.

(1) *The ground state:*

Determining the ground state $|0\rangle$ in the new representation by

$$c_j |0\rangle = a_k |0\rangle = b_q |0\rangle = 0 \quad (20)$$

one gets the energy $E''_{//}(0)$ of the ground state

$$\begin{aligned} E''_{//}(0) &= \langle H''_{//} \rangle = \langle H''_0 + H''_{e-lo} + H''_{e-so} \rangle \\ &= \frac{\lambda}{4} + \frac{\omega_c^2}{4\lambda} + \sum_k \omega_{lo} |f_k|^2 + \sum_q \omega_{so} |g_q|^2 + \frac{1}{2} \sum_k |f_k|^2 k_{//}^2 + \frac{1}{2} \sum_{k,k'} |f_k|^2 |f_{k'}|^2 k \cdot k' \\ &\quad + \sum_k [V_k^* \sin(zk_z) f_k^* + V_k \sin(zk_z) f_k] \exp\left(-\frac{k_{//}^2}{8} \left(\frac{1}{\lambda} + \frac{\lambda}{\omega_c^2}\right)\right) \\ &\quad + \sum_q [V_q^* \exp(-qz) g_q^* + V_q \exp(-qz) g_q] \exp\left(-\frac{q^2}{8} \left(\frac{1}{\lambda} + \frac{\lambda}{\omega_c^2}\right)\right). \end{aligned} \quad (21)$$

Minimizing $E''_{//}(0)$ with respect to $f_k(f_k^*)$ and $g_q(g_q^*)$ and neglecting higher order of f_k , one gets

$$E''_{//}(0) = \frac{\lambda}{4} + \frac{\omega_c^2}{4\lambda} + V_{e-lo}(0) + V_{e-so}(0) \quad (22)$$

Where $V_{e-lo}(0)$ and $V_{e-so}(0)$ are the correction energy induced by electron-LO phonon and electron-SO phonon interaction respectively, with

$$V_{e-lo} = - \sum_k \frac{|V_k|^2 \sin^2(zk_z) \exp\left(-\frac{k_{//}^2}{4} \left(\frac{1}{\lambda} + \frac{\lambda}{\omega_c^2}\right)\right)}{\frac{1}{2} k_{//}^2 + \omega_{lo}}, \quad (23)$$

$$V_{e-s0} = - \sum_q \frac{|V_q|^2 \exp(-2qz) \exp(-\frac{q^2}{4}(\frac{1}{\lambda} + \frac{\lambda}{\omega_c^2}))}{\omega_{so}} . \quad (24)$$

Considering the explicit forms of V_k and V_q , (23) and (24) can be reduced to

$$V_{e-lo} = -\frac{\sqrt{2}\alpha_l\omega_{lo}^{\frac{1}{2}}}{2} \int_0^\infty \frac{(1 - e^{-2k_{//}z}) \exp(-\frac{k_{//}^2}{4}(\frac{1}{\lambda} + \frac{\lambda}{\omega_c^2}))}{1 + \frac{k_{//}^2}{2\omega_{lo}}} dk_{//} , \quad (25)$$

$$V_{e-so} = -\sqrt{2}\alpha_s\omega_{so}^{\frac{1}{2}} \int_0^\infty \exp(-2qz) \exp(-\frac{q^2}{4}(\frac{1}{\lambda} + \frac{\lambda}{\omega_c^2})) dq . \quad (26)$$

In eq.(22) ,if neglecting $V_{e-lo}(0), V_{e-so}(0)$ and minimizing $E''_{//}(0)$ with respect to λ , one can obtain $\lambda = \omega_c$ and $E''_{//}(0) = \frac{1}{2}\omega_c$. Obviously, this is the electron ground state energy of Landau Level.

The effective Hamiltonian of the polaron system in the ground state H_{eff} is

$$H_{eff} = E''_{//}(0) + H_\perp = \frac{p_z^2}{2} + \frac{\lambda}{4} + \frac{\omega_c^2}{4\lambda} + V_{e-lo} + V_{e-so} + V_{img} , \quad (27)$$

with

$$V_{img} = \frac{e^2(\varepsilon_\infty - 1)}{4z(\varepsilon_\infty + 1)} .$$

(2) *The excited state:*

The excited state $|1\rangle$ in the new representation is

$$|1\rangle = c_j^\dagger |0\rangle = a_k^\dagger |0\rangle = b_q^\dagger |0\rangle \quad (28)$$

considering

$$\langle 1 | \exp(-iq \cdot \rho_0) | 1 \rangle = \exp(-\frac{q^2}{8\lambda} - \frac{\lambda q^2}{8\omega_c^2}) [1 - (\frac{q^2}{8\lambda} + \frac{\lambda q^2}{8\omega_c^2})] \quad (29)$$

similarly, one gets

$$E''_{//}(1) = \frac{3\lambda}{4} + \frac{3\omega_c^2}{4\lambda} + \omega_{lo} + \omega_{so} + V_{e-lo}(1) + V_{e-so}(1) \quad (30)$$

Where $V_{e-lo}(1)$ and $V_{e-so}(1)$ are the correction energy induced by electron-LO phonon and electron-SO phonon interaction of the excited state respectively, with

$$V_{e-lo}(1) = - \sum_k \frac{|V_k|^2 \sin^2(zk_z) \exp(-\frac{k_{//}^2}{4}(\frac{1}{\lambda} + \frac{\lambda}{\omega_c^2})) [1 - (\frac{k_{//}^2}{8\lambda} + \frac{\lambda k_{//}^2}{8\omega_c^2})]^2}{\frac{1}{2}k_{//}^2 + \omega_{lo}} , \quad (31)$$

$$V_{e-so}(1) = - \sum_q \frac{|V_q|^2 \exp(-2qz) \exp(-\frac{q^2}{4}(\frac{1}{\lambda} + \frac{\lambda}{\omega_c^2})) [1 - (\frac{q^2}{8\lambda} + \frac{\lambda q^2}{8\omega_c^2})]^2}{\omega_{so}} . \quad (32)$$

3. Discussion and Conclusion

Taking the polaron in polar crystal AgBr as an example, we perform a numerical evaluation. The parameters concerned are listed as follows: $\varepsilon_0=10.6$, $\varepsilon_\infty=4.68$, $\hbar\omega_{lo}=17.1\text{meV}$, $\hbar\omega_{so}=14.5\text{meV}$, $\alpha_l=1.56$, $\alpha_s=2.56$, $m_b=0.22m$, m is the free electron mass. All the above parameters are taken from [12].

Fig.1

Fig.2

Fig.1 shows the relationships between the induced potential $|V_{e-lo}(0)|$ resulting from the electron-LO phonon interaction, the induced potential $|V_{e-so}(0)|$ resulting from electron-SO phonon interaction, and their sum $|V_{e-lo}(0)| + |V_{e-so}(0)|$ and the coordinate z . From fig.1 we can see that the induced potential $V_{e-lo}(0)$ increase with increasing coordinate z , whereas $V_{e-so}(0)$ decrease with increasing coordinate z . Compared with the weak electron-phonon interaction case [13], $|V_{e-so}(0)|$ and $|V_{e-lo}(0)|$ are larger than the corresponding weak coupling ones, yet their lines tendency is similar to the weak coupling ones. When $z < 10\text{\AA}$, $|V_{e-so}(0)|$ is larger than $|V_{e-lo}(0)|$, whereas for $z > 35\text{\AA}$, $|V_{e-so}(0)|$ becomes smaller compared with $|V_{e-lo}(0)|$ and so $|V_{e-lo}(0)|$ is the dominant term. $|V_{e-lo}(0)| + |V_{e-so}(0)|$ decreases with increasing z . When $z > 35\text{\AA}$, $|V_{e-lo}(0)| + |V_{e-so}(0)|$ approaches $|V_{e-lo}(0)|$ because $|V_{e-so}(0)|$ is much smaller compared with $|V_{e-lo}(0)|$.

Fig.2 show the induced potentials as a function of the electron coordinate z for different magnetic fields. In fig.2, the dot-line stands for the case when $B=4\text{T}$ and the solid-line stands for the $B=8\text{T}$ case. From fig.2, we can see that $|V_{e-lo}(0)|$ and $|V_{e-so}(0)|$ for $B=8\text{T}$ are larger than the corresponding ones for $B=4\text{T}$. This result show that external magnetic field can enhance the interaction between an electron and phonons. Let us give a possible physical explanation of the result. When magnetic field is applied, the polarizability of the crystal increases and the density of phonons increases. Because the strength of the electron-phonon interaction is proportional to the number of phonons, the interaction energies, for both $|V_{e-lo}(0)|$ and $|V_{e-so}(0)|$, increase with increasing magnetic field strength.

Fig.3

Fig.3 illustrates the energy difference induced by the electron-LO (SO) phonon interaction between the excited and ground states. From fig.3 one can see that the difference between $V_{e-so}(1)$ and $V_{e-so}(0)$ decreases, yet the difference between $V_{e-lo}(1)$ and $V_{e-lo}(0)$ increases as the coordinate z increases. As z is small ($z < 10\text{\AA}$) the magnitude of $V_{e-so}(1) - V_{e-so}(0)$ is much larger than that of $V_{e-lo}(1) - V_{e-lo}(0)$, and when $z > 33\text{\AA}$ $|V_{e-so}(1) - V_{e-so}(0)|$ becomes less than $|V_{e-lo}(1) - V_{e-lo}(0)|$. These results give further implication that the electron-SO phonon interaction play a dominant role as electron are near the polar crystal surface.

In summary, by applying variational method, the strong electron-surface optical(SO) phonon interaction and the weak electron-longitudinal optical (LO) phonon interaction are studied systematically in present paper. The formula of induced energies $V_{e-so}(0)$, $V_{e-lo}(0)$, $V_{e-so}(1)$, $V_{e-lo}(1)$ are given. The numerical results show that as the distance between the electron and the polar crystal surface increases, the electron-LO phonon interaction energy increases yet the electron-SO phonon interaction energy decreases. The numerical results also show that both electron-LO and electron-SO phonon interaction are enhanced as the magnetic field strength increases.

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Figure Captions

Fig.1. $|V_{e-so}(0)|$, $|V_{e-lo}(0)|$, and $|V_{e-so}(0)| + |V_{e-lo}(0)|$ as a function of coordinate z .

Fig.2. $|V_{e-so}(0)|$ and $|V_{e-lo}(0)|$ as a function of coordinate z for different magnetic fields. The solid line and the dot line represent $B=8T$ and $B=4T$, respectively.

Fig.3 $|V_{e-ph}(1) - V_{e-ph}(0)|$ as a function of coordinate z at $B=10T$.





